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APPLICANTS

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** CONTINUING DATA *****
None

** FOREIGN APPLICATIONS *****
 TAIWAN 091124151 10/16/2002

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| Foreign Priority claimed 35 USC 119 (a-d) conditions met | <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> yes <input checked="" type="checkbox"/> no <input type="checkbox"/> Met after <i>Allowance</i> | STATE OR COUNTRY TAIWAN | SHEETS DRAWING 4 | TOTAL CLAIMS 21 | INDEPENDENT CLAIMS 1 |
| Verified and Acknowledged | <i>A. J. [Signature]</i> Examiner's Signature | | | | |
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TITLE
 Method of growing single crystal Gallium Nitride on silicon substrate

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| FILING FEE | <input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time) |
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